

Beam losses at SPS flat-bottom

M. Schwarz

Acknowledgements:

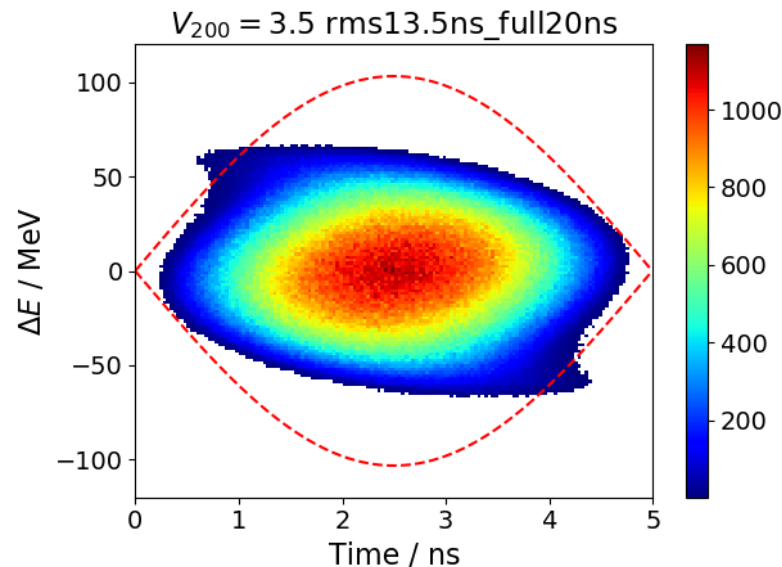
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Content

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- Measurements
 - Flat-bottom losses
 - Capture losses
- Simulations
 - Model of SPS one-turn delay feedback
 - Capture losses
 - Improvements from future feedback system
- Summary

Sources of losses

1. Losses at injection, possible sources:
 1. Longitudinal effects (bunch shape from PS, uncaptured PS beam,...)
 2. SPS LLRF system
2. Losses at flat-bottom, possible sources:
 1. Momentum aperture and transverse emittance
 2. Full bucket (intensity effects, noise from LLRF)

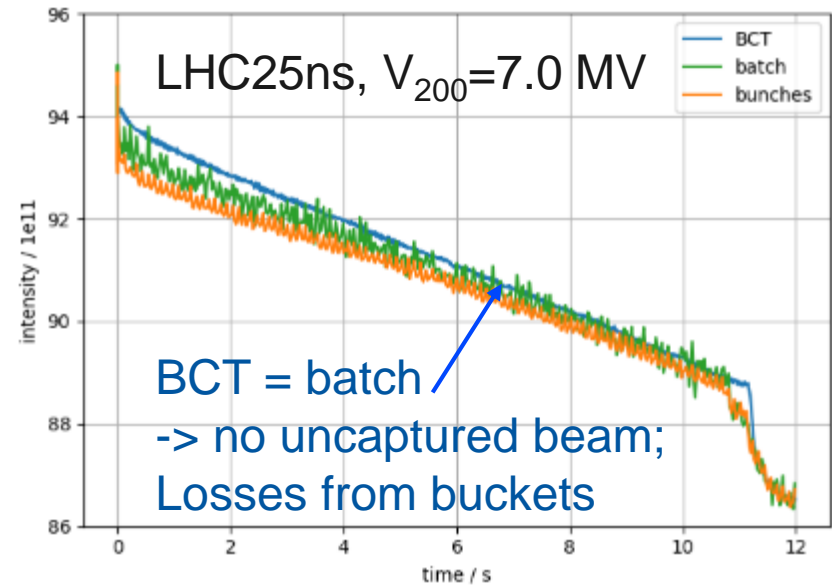
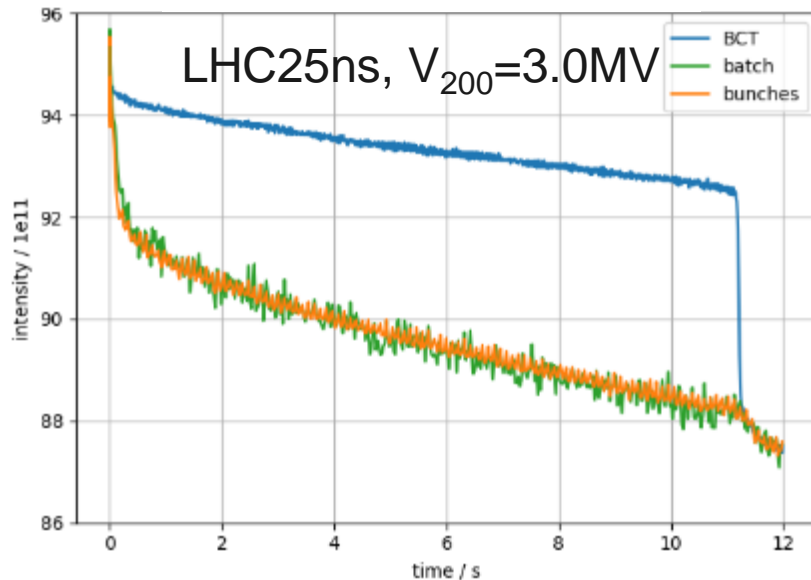


Simulated PS bunch in
SPS RF-bucket
(courtesy of A. Lasheen)

- Bunch fills entire RF-bucket
- Larger capture voltage leads to large emittance due to filamentation -> problem to accelerate
- Solution? Increase V_{200} on flat-bottom after capture to prevent particles escaping from bucket

Measurement with different V_{200}

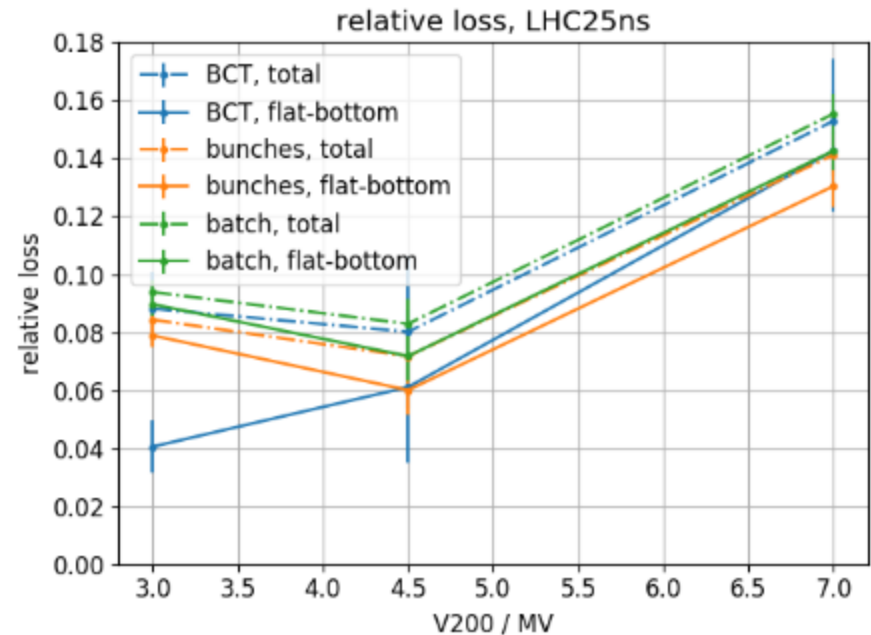
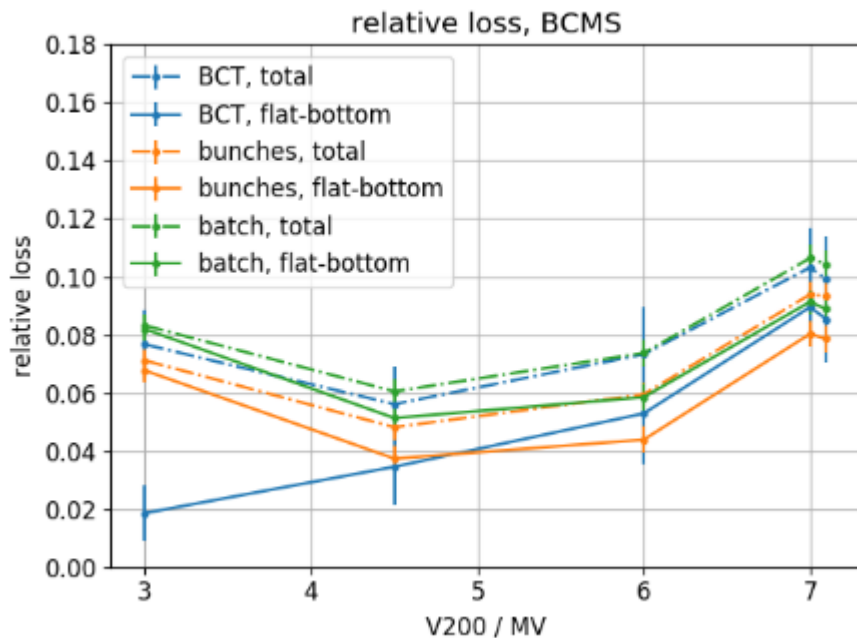
- 72 bunches, 25ns spacing, $1.3e11$ particles per bunch
- LHC25 (Q20), $V_{800} = 0.1 V_{200}$
- Flat-bottom 0-11.1s, data up to first part of ramp (11.830s ~ 29 GeV)
- Capture at $V_{200}=4.5$ MV (nominal case), **change V_{200} at flat-bottom** (ramp 50ms to 100ms after injection and at 10.75s)



- Limited by momentum aperture in Q20
- Less losses for smaller transverse emittance -> use BCMS (only 48 bunches)

Losses for different transverse emittances

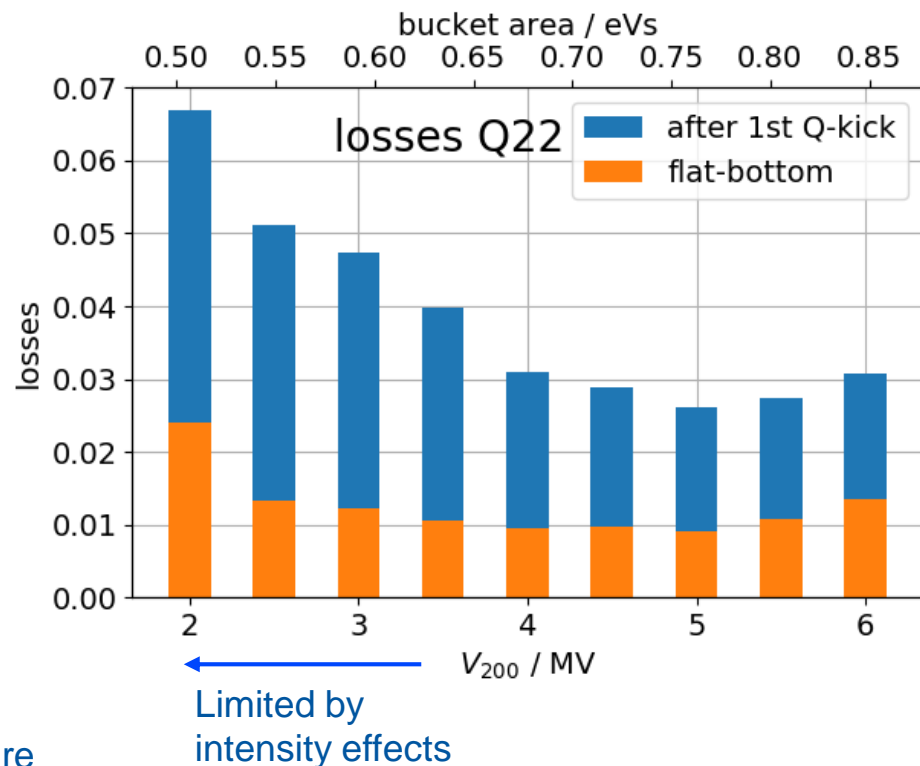
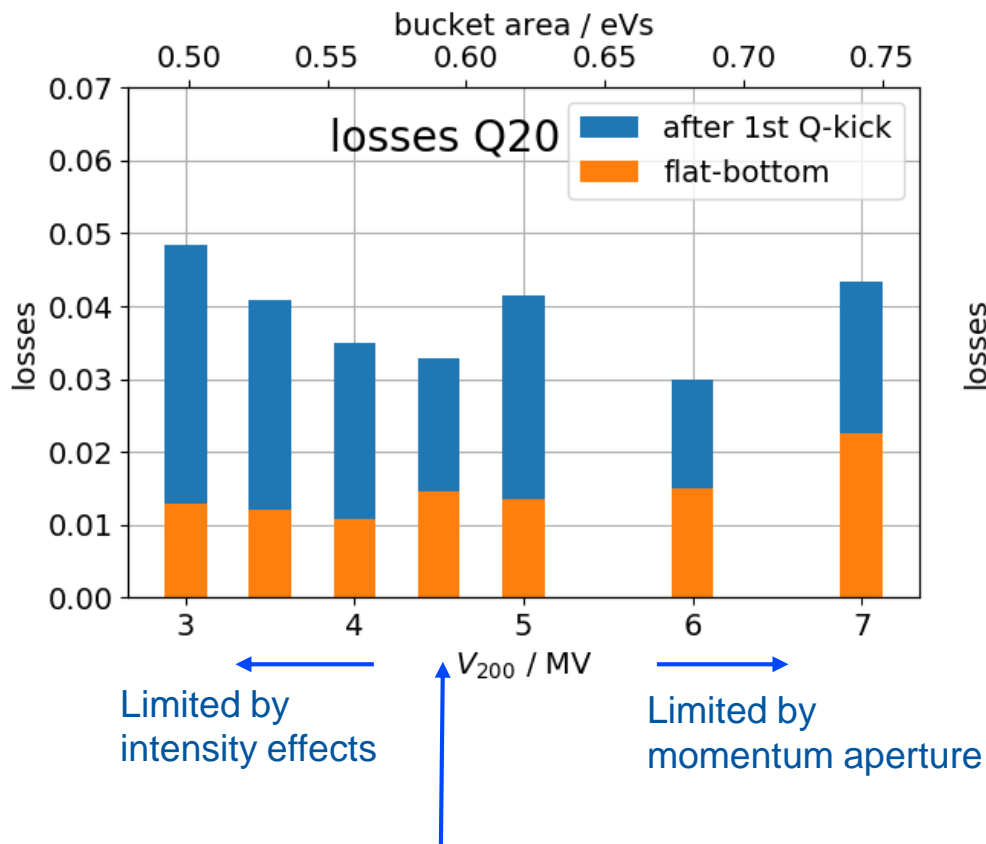
- **48 bunches**, 25ns spacing, **1.52e11 particles per bunch**
- $V_{800} = 0.1 V_{200}$
- Flat-bottom 0-11.1s, ramp to 450GeV 11.1-19.5s, flat-top 19.5-20s
- Here: data from injection to first part of ramp (11.830s ~ 29 GeV)
- Inject at $V_{200}=4.5\text{MV}$ (nominal case), **change V_{200} at flat-bottom** (ramp 50ms to 100ms after injection and at 10.75s to 10.85s)
- Compare Q20 **LHC25ns** and **BCMS** (transverse emittance reduced by factor 2)



- Less losses for BCMS (smaller transverse emittance)
- Minimal losses at $V_{200}=4.5\text{MV}$

Scan of RF-bucket area and optics

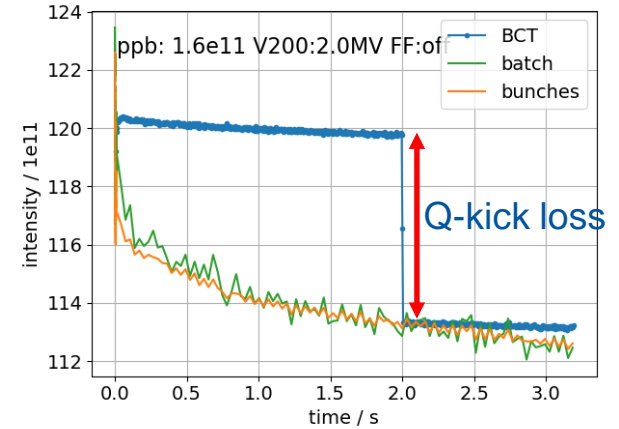
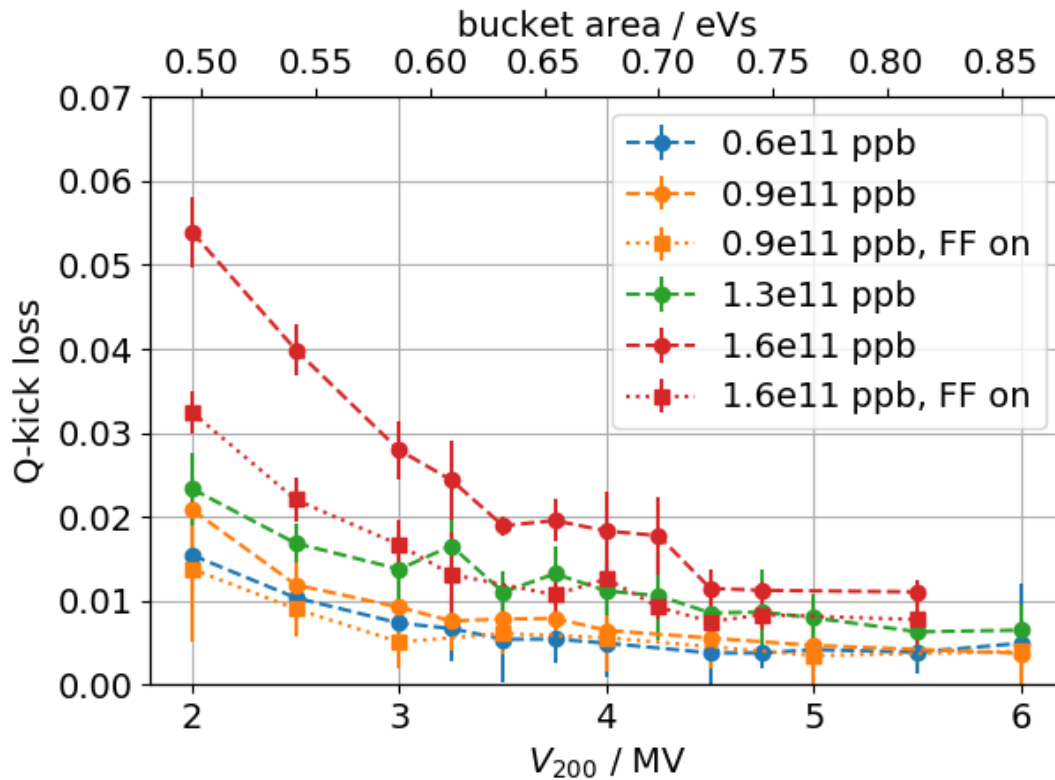
- **48 bunches**, 25ns spacing, **1.35e11 particles per bunch**
- V_{800} off; Feedback on; Feedforward off
- Flat-bottom 0-11.1s, ramp starts at 11.1s, tune-kick 2s after injection
- Compare **BCMS Q20** and **BCMS Q22**



Optimum at $V_{200}=4.5\text{MV}$ for Q20
(operational setting)

Different voltages and intensities

- 72 bunches, 25ns spacing, Q22
- V_{800} off; Feedback on; Feedforward **on/off**
- Remove uncaptured beam via tune kick at 2s



- Losses saturate at high V_{200} : uncaptured halo from PS
- Losses increase with intensity for low V_{200} : induced voltage in SPS

Longitudinal beam dynamics simulations

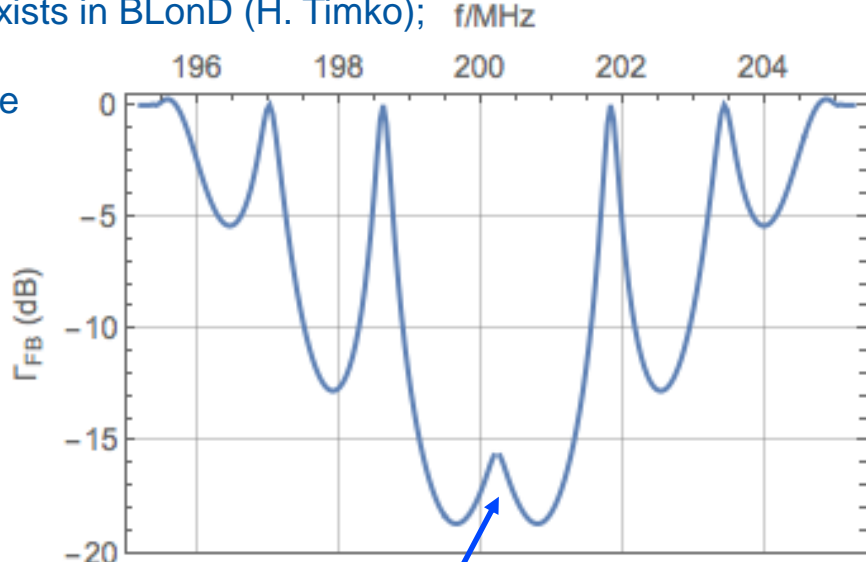
- Use simulated PS-bunch (courtesy A. Lasheen)
- Model injection by creating 72 bunches (25ns spacing) at the center of SPS RF-bucket
- impedance model:
 - present full SPS impedance model
 - impedances for long and short 200MHz TWC cavities

Dynamic model of SPS 1-turn delay feedback system exists in BLongD (H. Timko); need to adjust gain margin

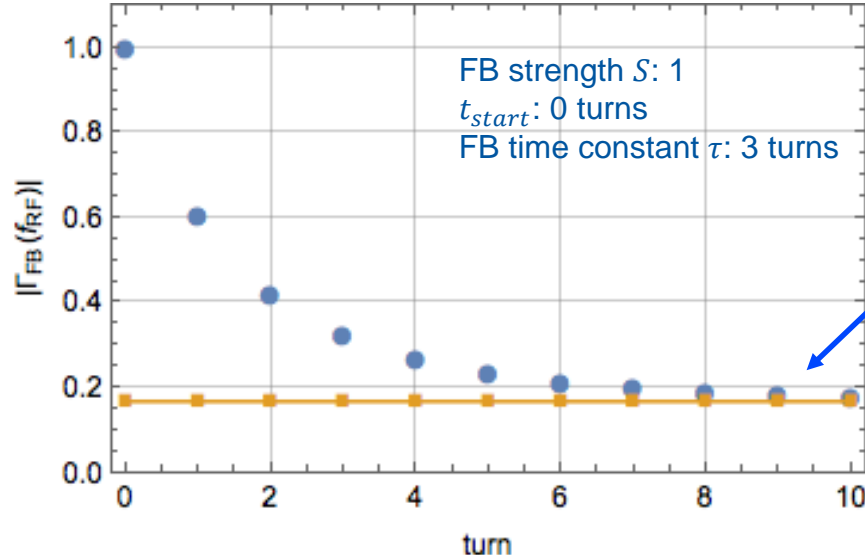
Here: model effect of feedback by multiplying impedance with feedback-reduction factor:

$$Z_n = Z_{n-1} \Gamma_{FB} \text{ [P. Baudrenghien, Charmonix X, 2001]}$$

- Continuously increase feedback strength:
 - $Z_n = Z_{n-1} (\Gamma_{FB})^{S \text{ att}(t)}$ with $\text{att}(t) = 1 - e^{-(t-t_{start})/\tau}$
 - 'FB strength S ', 'start time t_{start} ', 'FB time constant τ '
 - individual parameters for 5- and 4- sections cavities



$\Gamma_{FB} = -15.5$ dB at f_{RF}
(i.e. $Z(f_{RF})$ multiplied by factor 0.17)

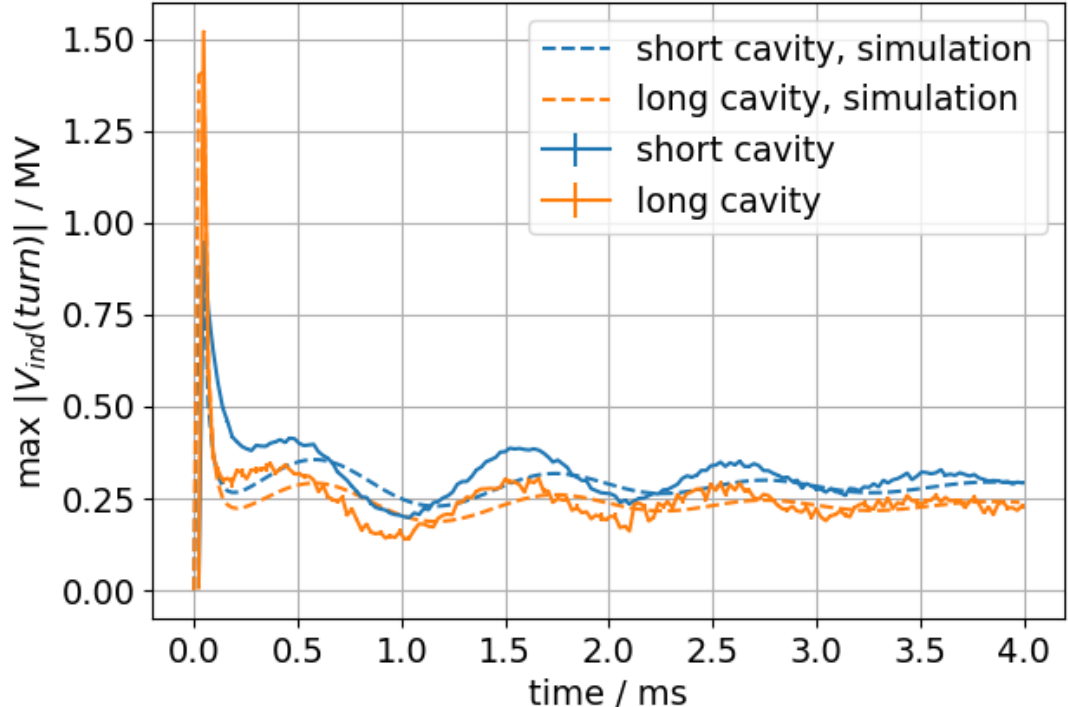


Calibration of feedback model parameters

- Measure beam loading in cavities at f_{RF}
- Simulate beam loading:
 - filter f_{RF} component of $V_{cav}(t)$
 - amplitude = $|V_{cav}(t)|$
- Use maximum amplitude at each turn
- Adjust 'FB strength S ', 'start time t_{start} ', and 'FB time constant τ ' such that simulated amplitude agrees with measured one
- Fit function: $f(t) = A \sin(\omega t + \varphi) \exp(-t/\tau) + L$

	Short cavity measured	Short cavity simulation	Long cavity measured	Long cavity simulation
A / kV	2.01	1.29	1.15	1.07
T / ms	1.02	1.05	0.98	1.05
τ / ms	1.61	1.36	2.03	1.35
L / kV	302	283	235	233

ppb: 1.48e11 V_{200} :4.5MV

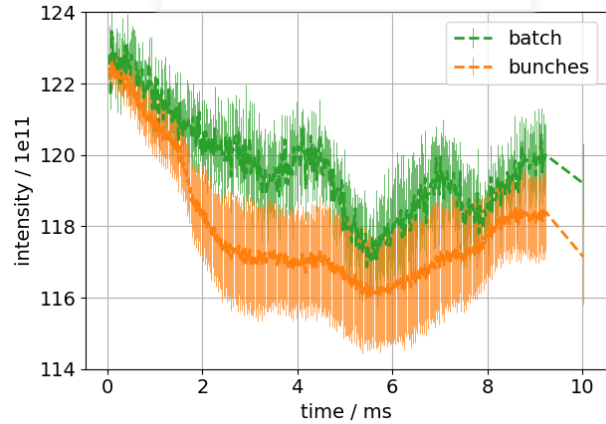


- Quadrupole oscillations ($0.5T_{s0} \sim 0.94ms$) due to initial mismatch
- Good general agreement between simulations and measurement
 - Model has shorter transient than measurements
 - Model predicts smaller quadrupole oscillation amplitude
 - Asymptotic behavior agrees very well

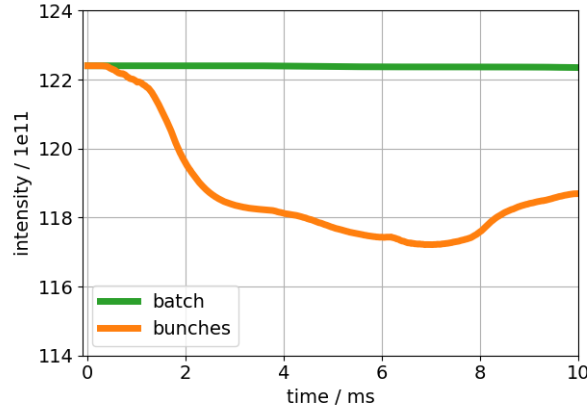
Comparison of measured and simulated losses

- 72 bunches (25ns spacing) and Q22 in both measurement and simulation
- Measured and simulated intensity obtained by integrating profile +/-0.575 RF-buckets around bunch peak
- Measurements and simulations with feedback and phase loop
- Example with highest intensity (1.7×10^{11} ppb) in measurements and low V_{200} voltage (2.0MV)

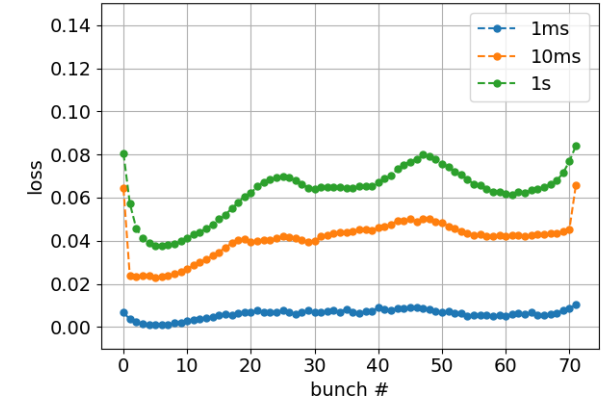
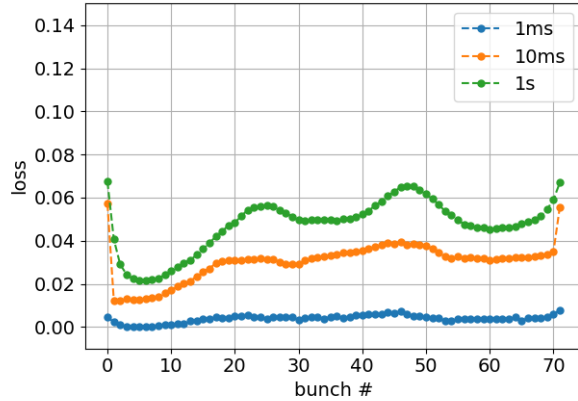
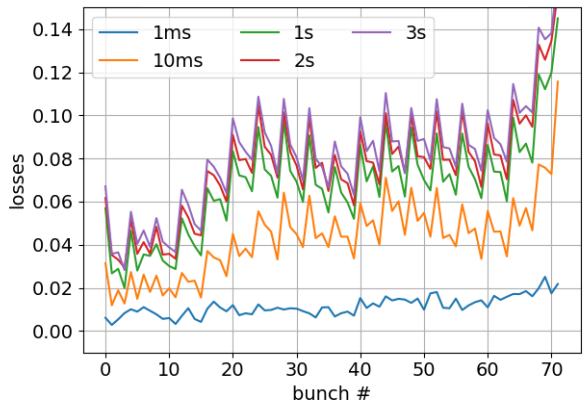
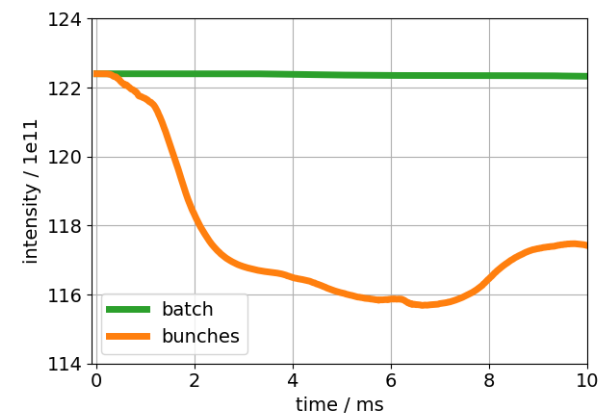
Measurement



Simulation (distribution 2)



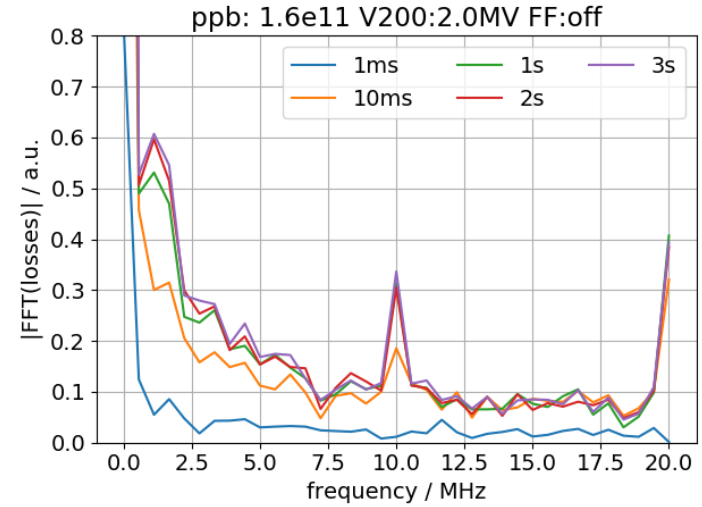
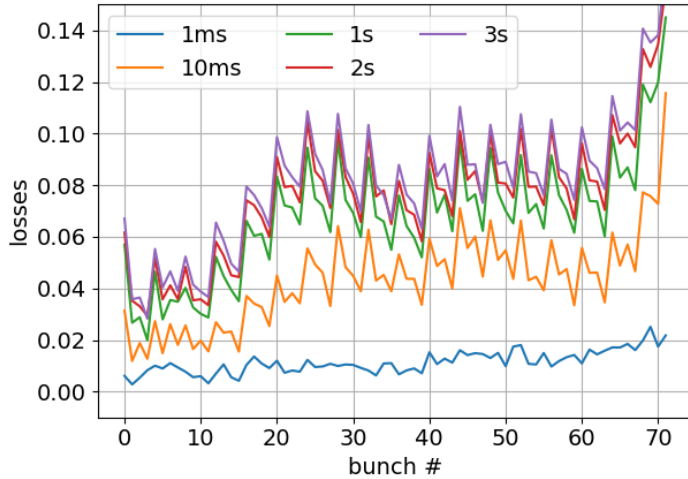
Simulation (distribution 3)



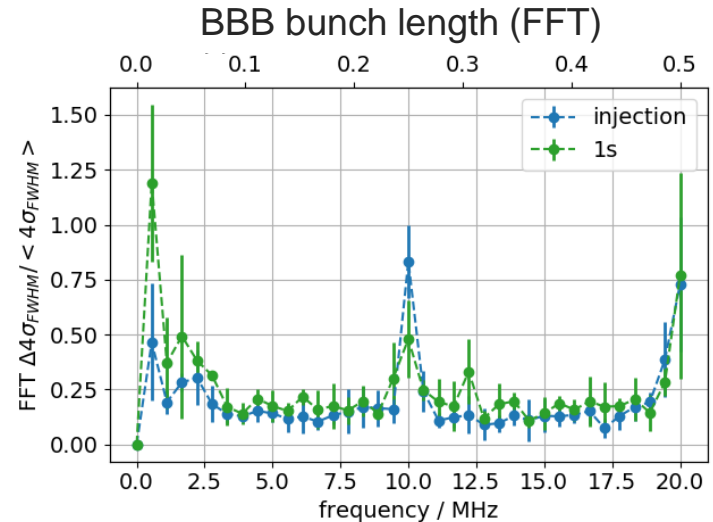
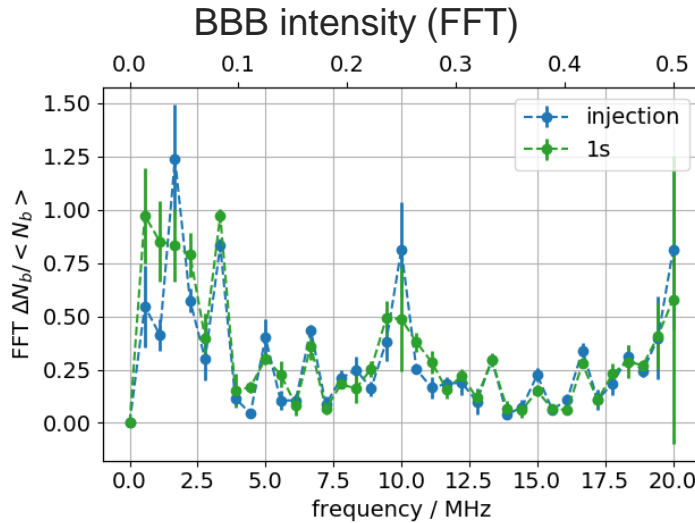
- Qualitative and quantitative agreement
 - ... but no strong rise of simulated losses at end of batch
 - ... simulated bunch-by-bunch losses don't display 'oscillation'

Measured oscillation in bunch-by-bunch loss pattern

- Notice 10 & 20 MHz oscillation in measured bunch-by-bunch loss pattern (every 4th & 2nd bunch) present after 10 ms



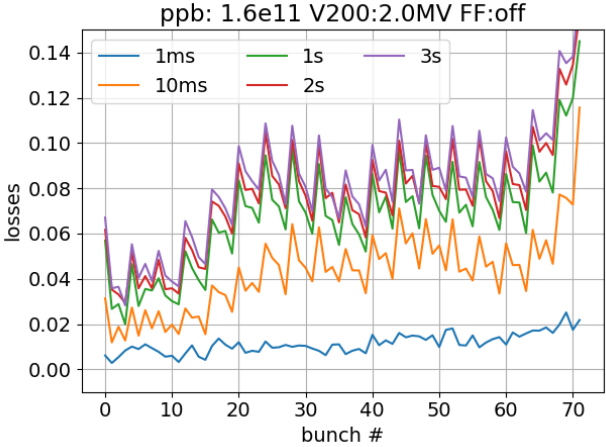
- Same oscillations also present in bunch-by-bunch intensity and bunch length from injection



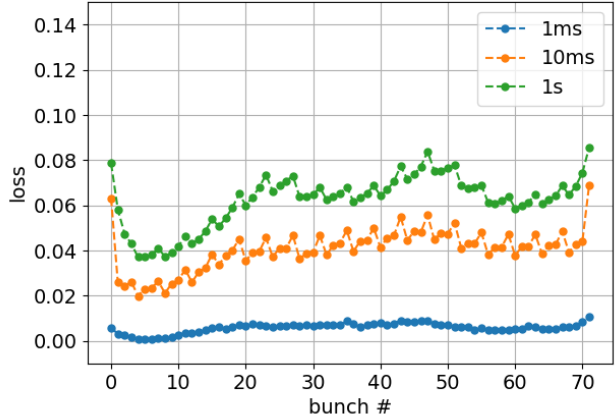
Comparison of measured and simulated losses

- In simulation use
 - a) same distribution with different intensities (# macro-particles)
 - b) distributions with different bunch lengths

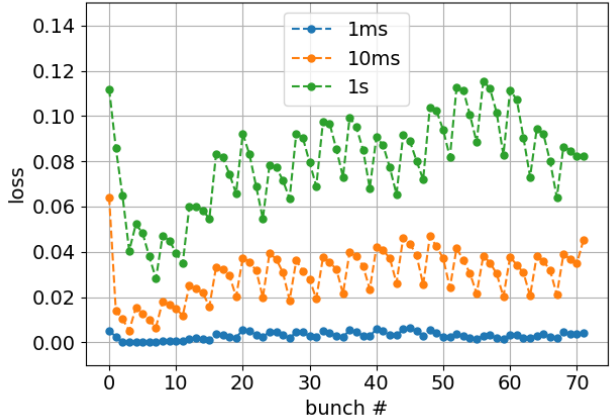
Measurement



Simulation a)
intensity modulation



Simulation b)
bunch length modulation

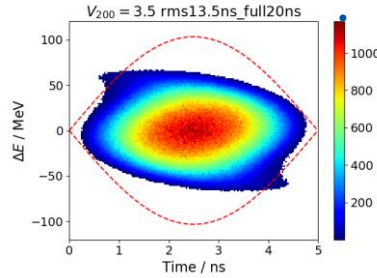


- Simulated bunch-by-bunch losses display oscillation
 - Varying bunch shape has stronger influence than varying intensities
- Presently, injected bunches from PS are adjusted to have equal intensities

Simulated losses for high intensity, $2.6e11$ ppb

Simulation parameters **present**:

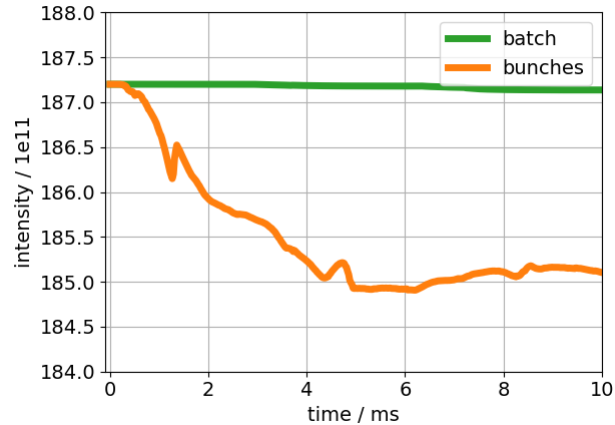
- 72 bunches, $2.6e11$ ppb
- $V_{200} = 3.5$ MV
- Feedback strength at **-15 dB reduction**
- Phase loop **averages over 12 bunches**
- Two 5-section and two 4-section cavities
- **Present** SPS impedance model



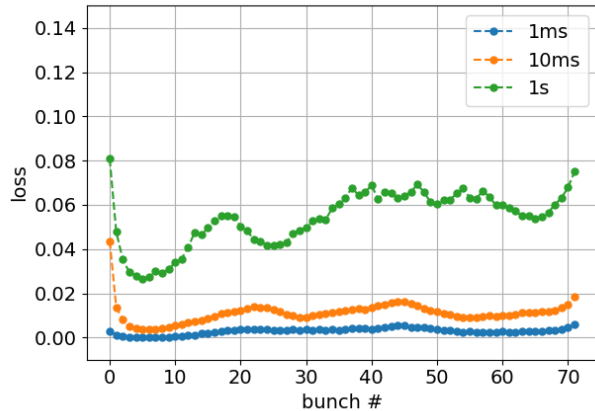
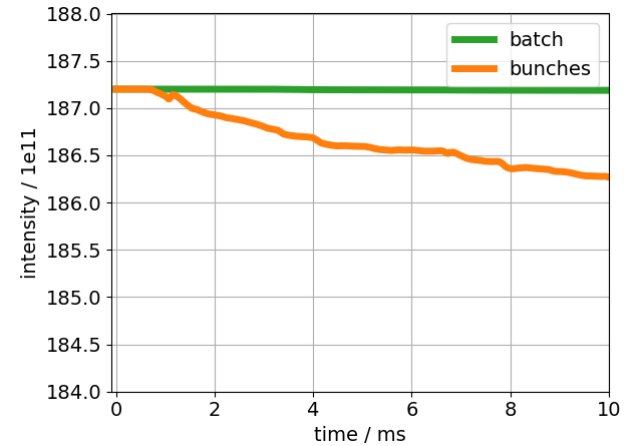
Simulation parameters **future**:

- 72 bunches, $2.6e11$ ppb
- $V_{200} = 3.5$ MV
- Feedback strength at **-26 dB reduction**
- Phase loop **averages over all bunches**
- Two 4-section and four 3-section cavities
- **Future** SPS impedance model

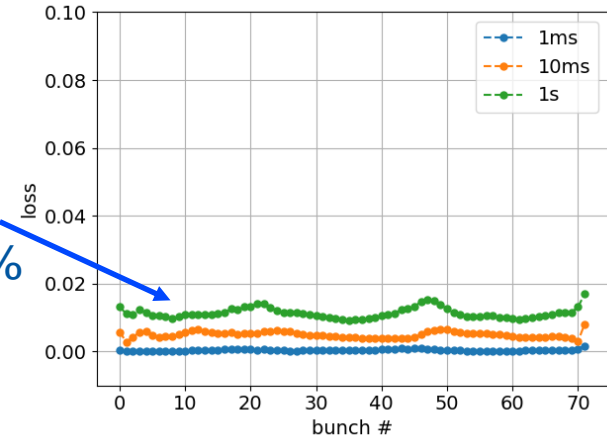
present



future



Losses below 2%



Summary

Two types of losses in the SPS:

- Capture losses
- Flat-bottom losses

Measured dependence of flat-bottom losses:

- Momentum aperture
- Transverse emittance

Capture losses depend on:

- Bunch shape coming from PS
- Beam intensity and voltage at injection

Beam simulations:

- Use 72 bunches and present SPS impedance model
- Model feedback system by impedance reduction
- Good agreement between simulation and measurements
- With future setup (FB, cavities, SPS impedance) simulated capture losses below 2% for 2.6×10^{11} ppb
- Need to investigate stability of simulation for long (1s) simulation times

Planned MDs:

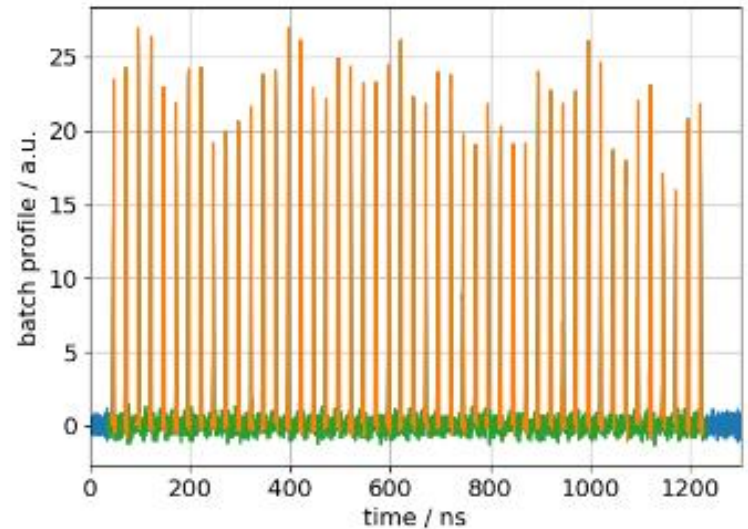
- Study impact of FF on flat-bottom losses
- Losses at higher intensities

Thank you for your attention

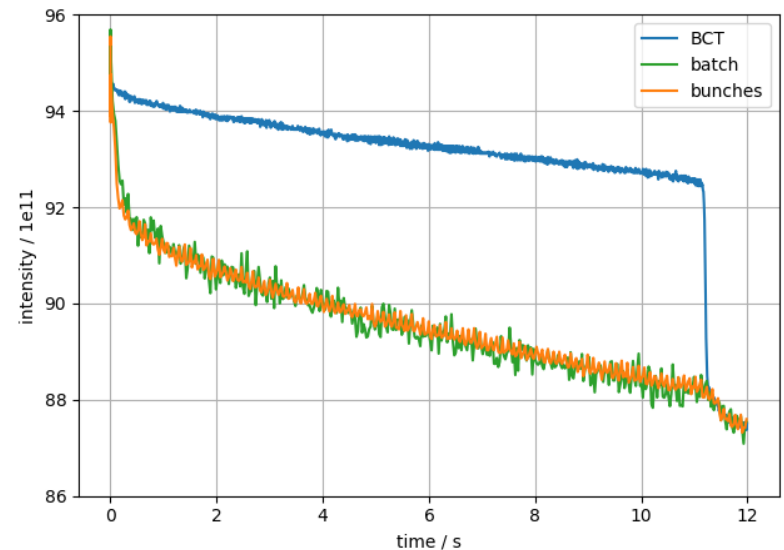
Appendix

Measurements of losses

- Measure longitudinal beam profiles
 - Obtain intensity of bunches by finding peaks (assumed to be center of bunch) and integrate profile in interval $[-0.575, +0.575]$ RF-buckets
 - Obtain intensity of batch by integrating also parts between bunches
- Use same method also for simulated beam profiles to compare with measurements



- Measure intensity in SPS with BCT
- Use BCT intensity to calibrate intensity from beam profiles
- Need to ensure that no uncaptured beam is in SPS -> use tune-kicker or ramp

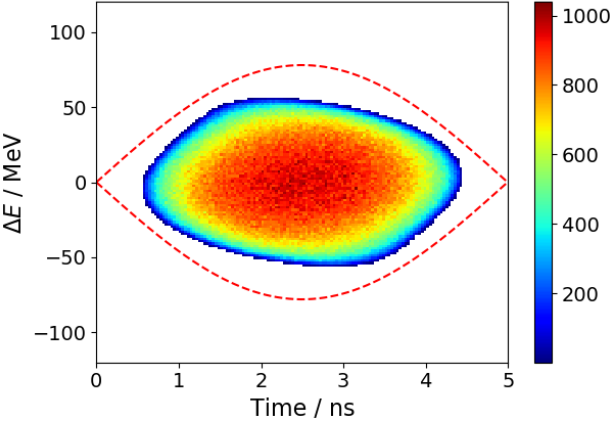


Simulated particle distributions used

- Use different bunch distributions simulated in the PS (courtesy of A. Lasheen)
 - Out of the 4M macro-particles, randomly select 1M macro-particles for tracking in the SPS for each of the 72 bunches
 - Place bunches at center of bare RF-bucket
 - Use 'impedance reduction' method to simulate SPS one-turn delay feedback
- Full SPS impedance model

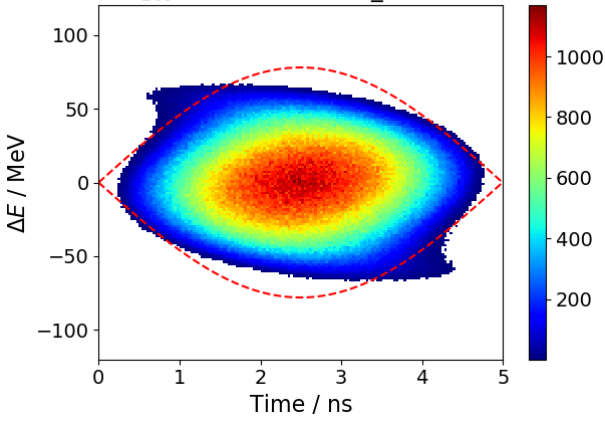
Distribution 1

$V_{200} = 2.0$ rms13.0ns_full15ns



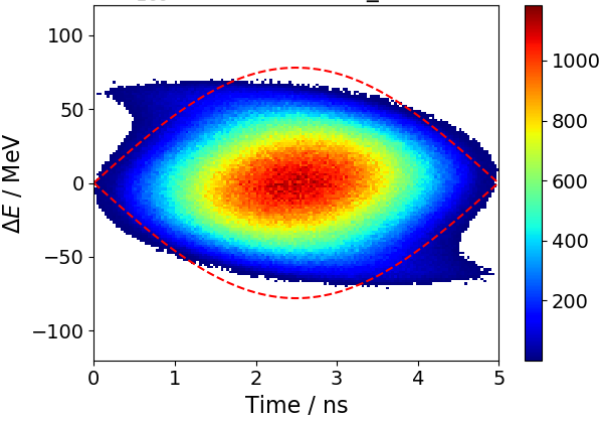
Distribution 2

$V_{200} = 2.0$ rms13.5ns_full20ns

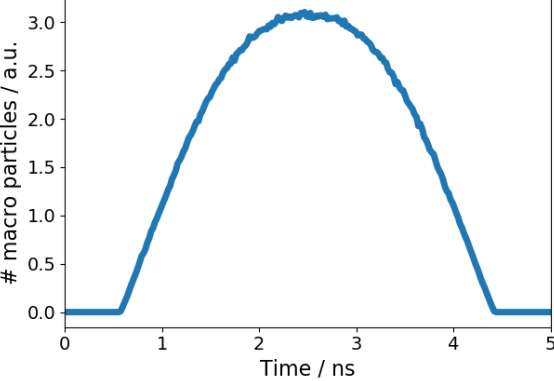


Distribution 3

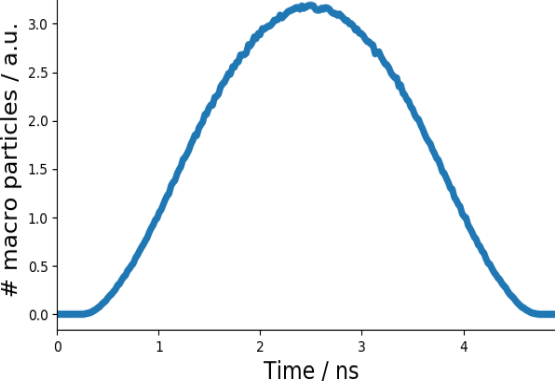
$V_{200} = 2.0$ rms14.0ns_full25ns



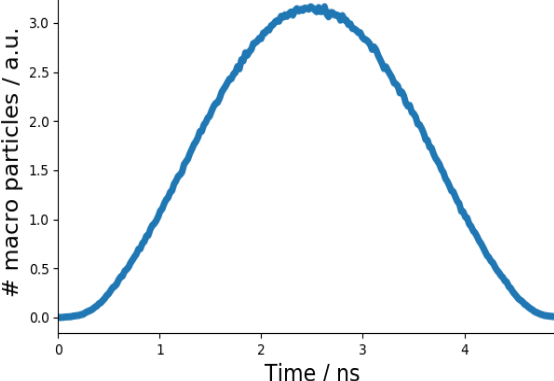
rms13.0ns_full15ns



rms13.5ns_full20ns



rms14.0ns_full25ns

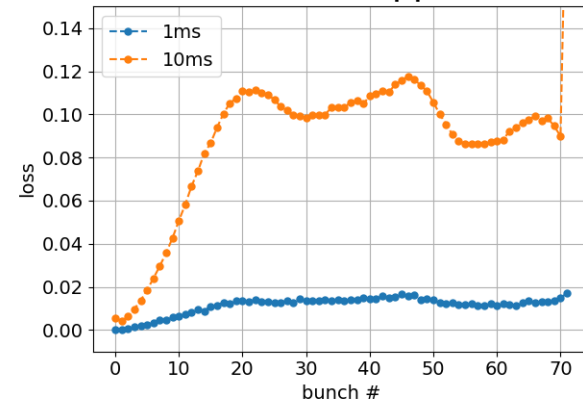
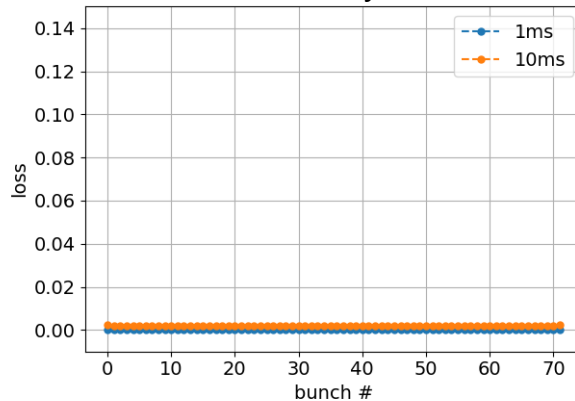
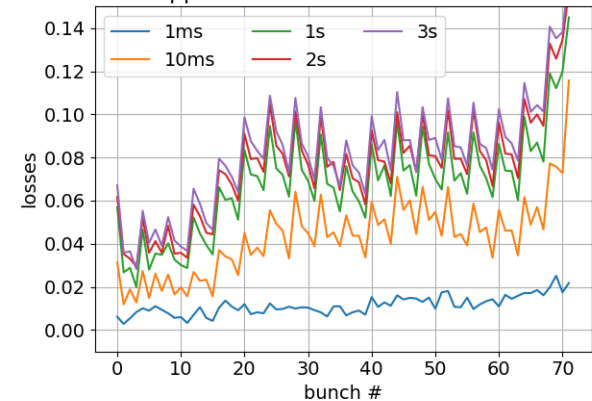


Bunch-by-bunch losses; distribution 2

ppb: 1.6e11 V200:2.0MV FF:off

0 intensity

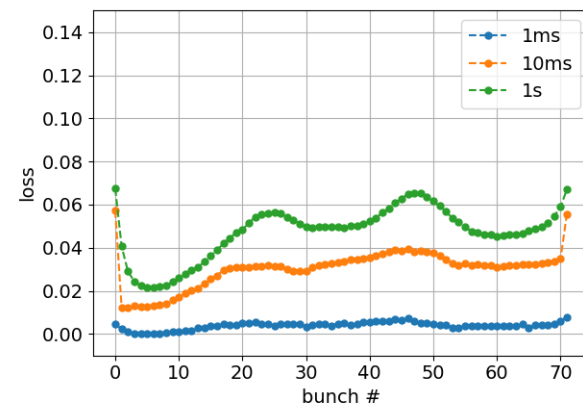
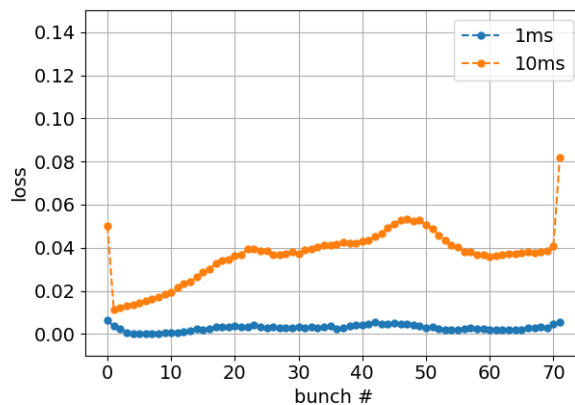
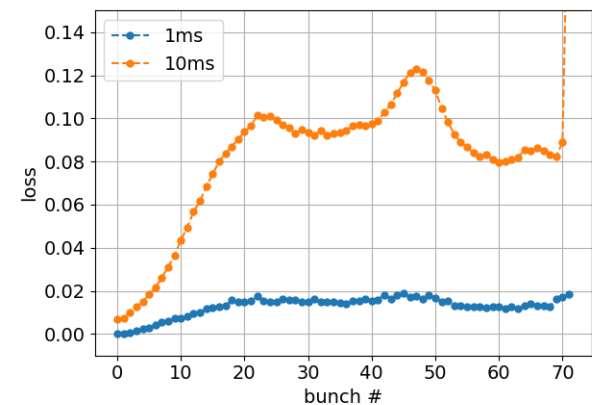
1.7e11 ppb



prev + SPS impedance

prev + PL (1st bunch)

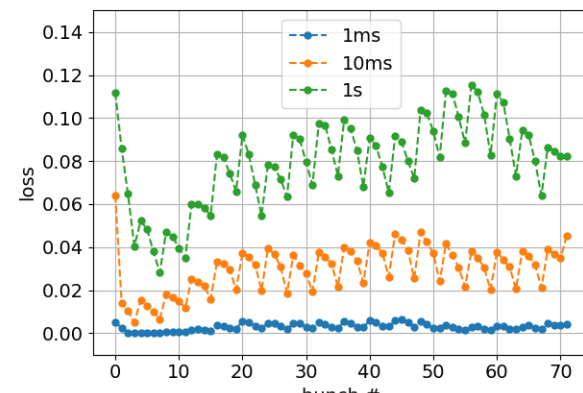
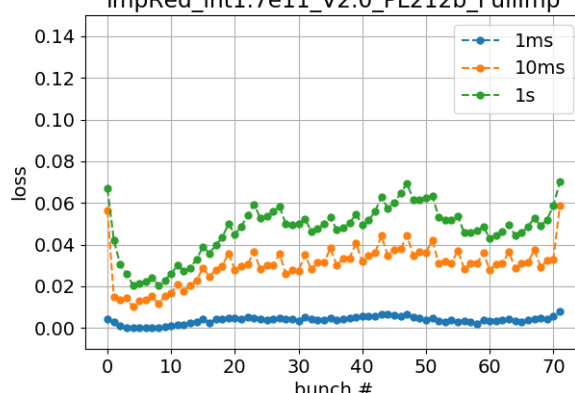
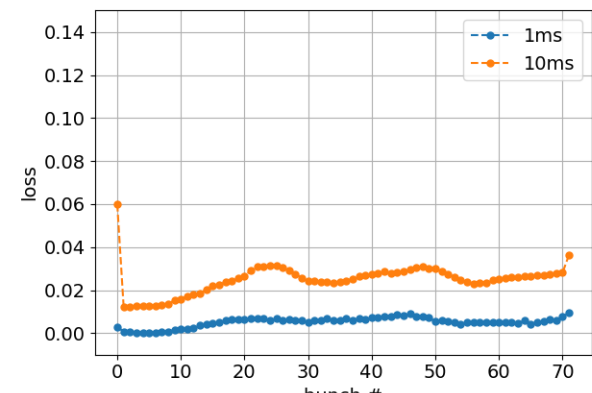
prev + PL (12 bunches) = standard



prev + PL (72 bunches)

standard + intensity modulation
ImpRed_int1.7e11_V2.0_PL212b_Fullimp

standard + length modulation

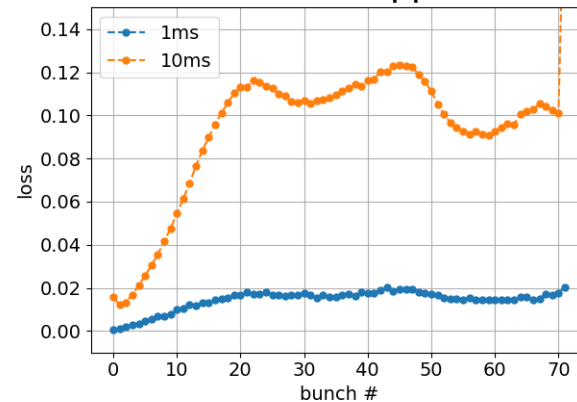
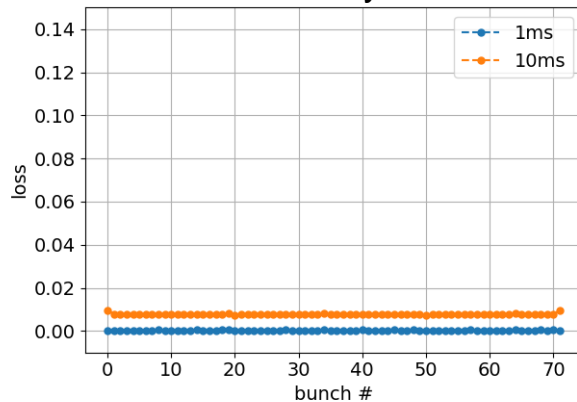
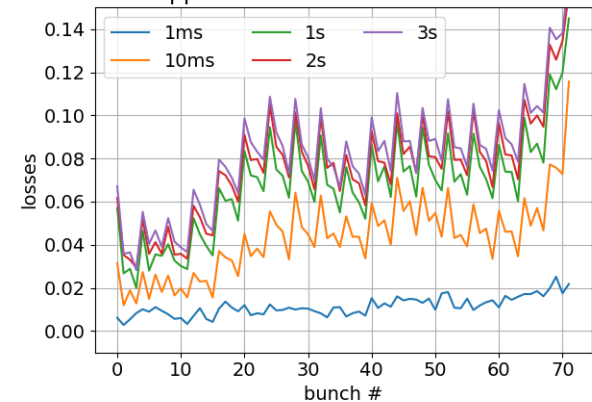


Bunch-by-bunch losses; distribution 3

ppb: 1.6e11 V200:2.0MV FF:off

0 intensity

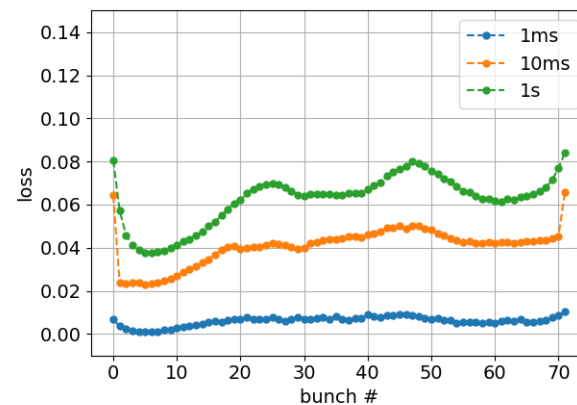
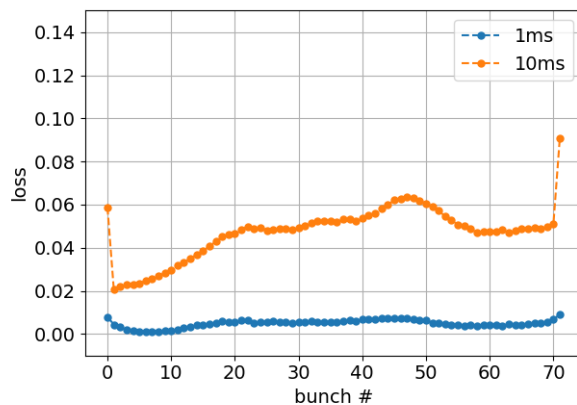
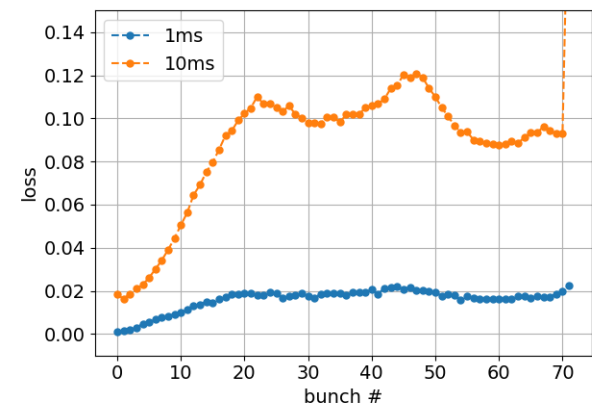
1.7e11 ppb



prev + SPS impedance

prev + PL (1st bunch)

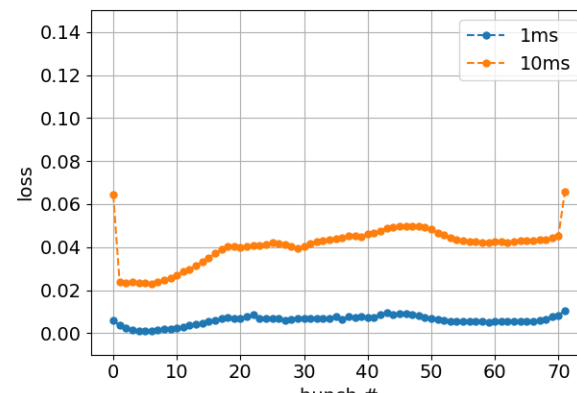
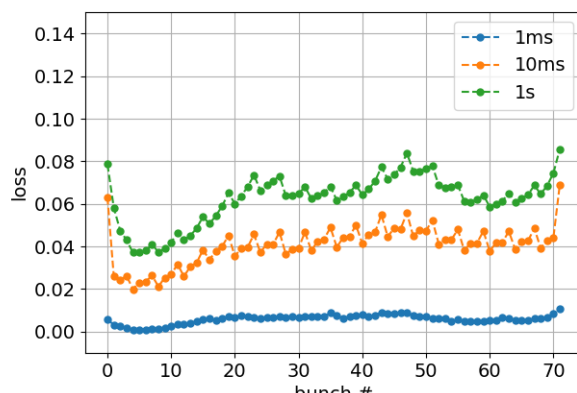
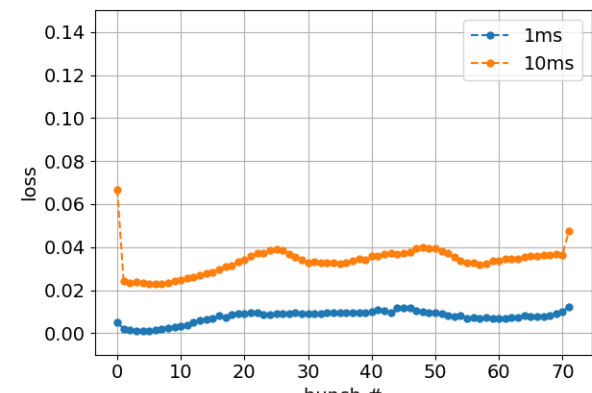
prev + PL (12 bunches) = standard



prev + PL (72 bunches)

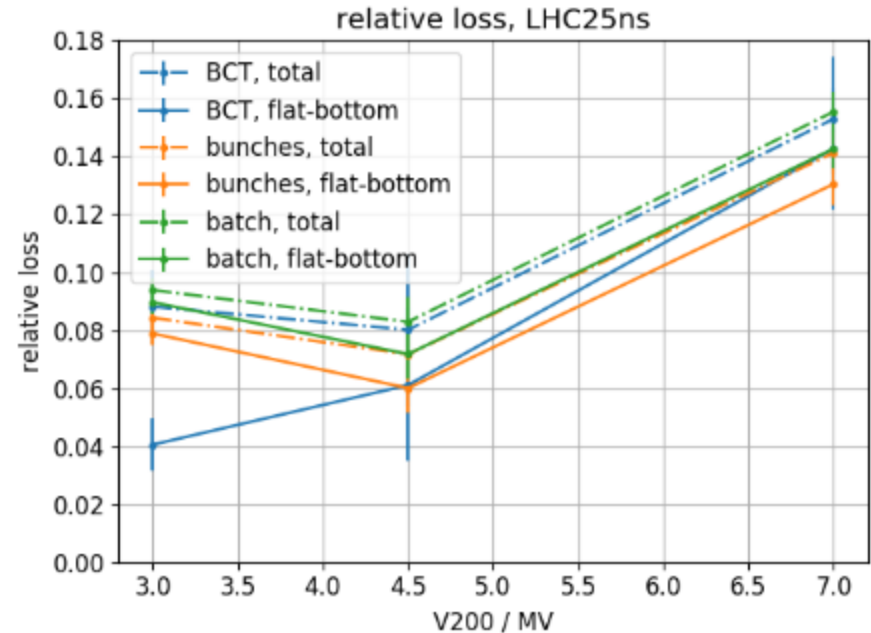
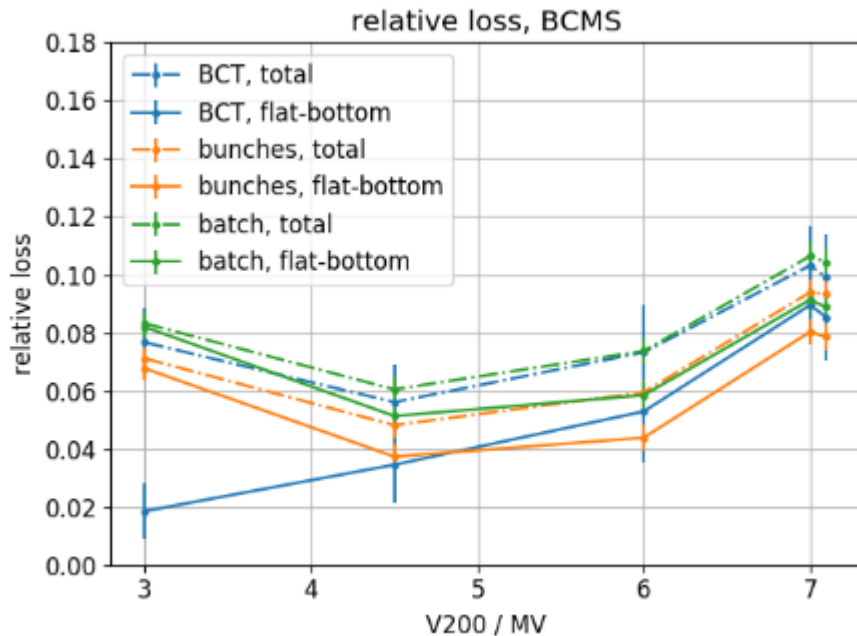
standard + intensity modulation

standard, 2M macro part pb



Losses for different transverse emittances

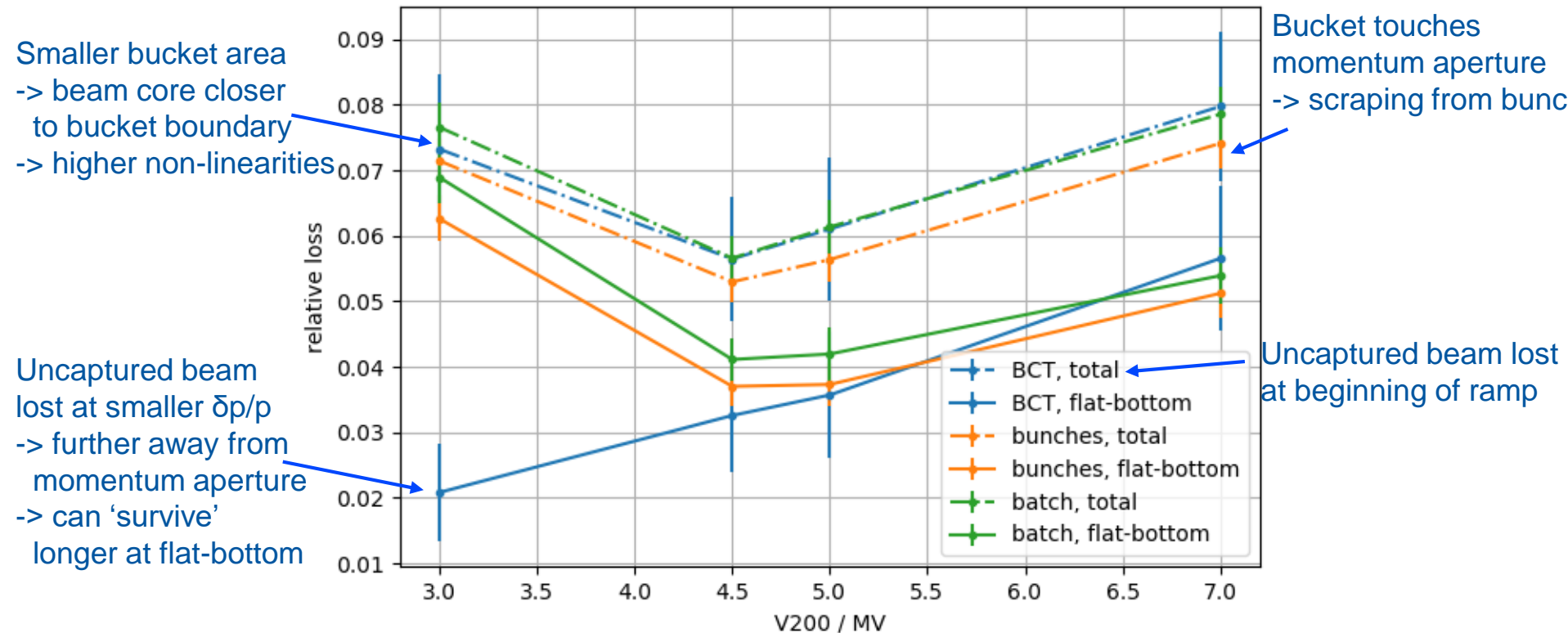
- **48 bunches**, 25ns spacing, **1.52e11 particles per bunch**
- $V_{800} = 0.1 V_{200}$
- Flat-bottom 0-11.1s, ramp to 450GeV 11.1-19.5s, flat-top 19.5-20s
- Here: data from injection to first part of ramp (11.830s ~ 29 GeV)
- Inject at $V_{200}=4.5\text{MV}$ (nominal case), **change V_{200} at flat-bottom** (ramp 50ms to 100ms after injection and at 10.75s to 10.85s)
- Compare Q20 **LHC25ns** and **BCMS** (transverse emittance reduced by factor 2)



- Less losses for BCMS (smaller transverse emittance)
- Minimal losses at $V_{200}=4.5\text{MV}$

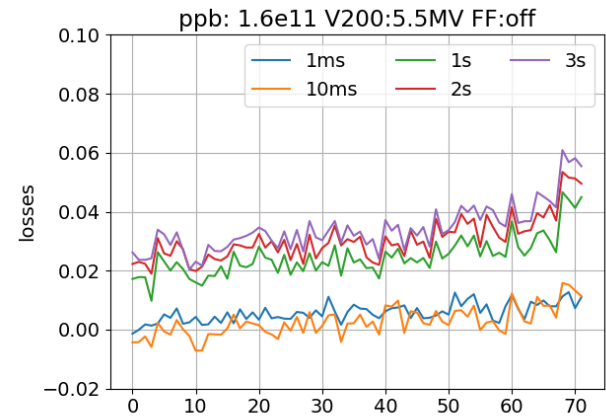
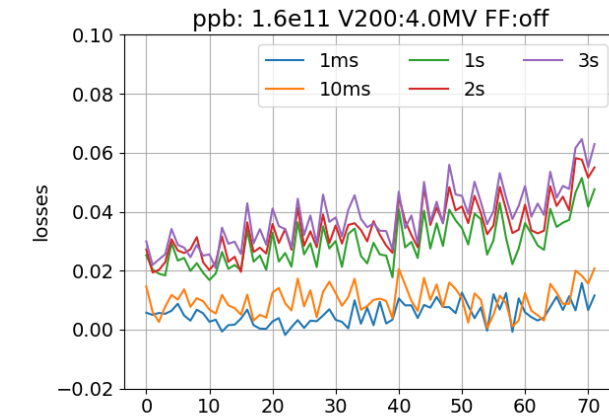
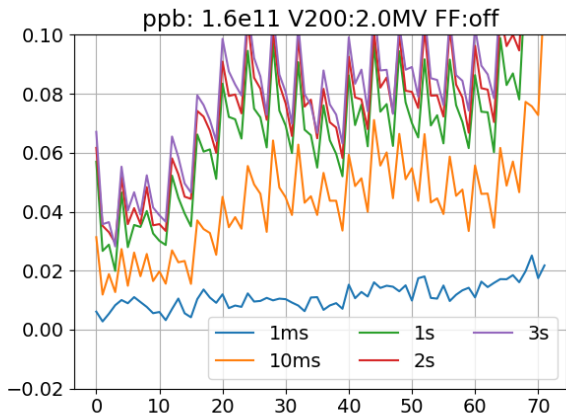
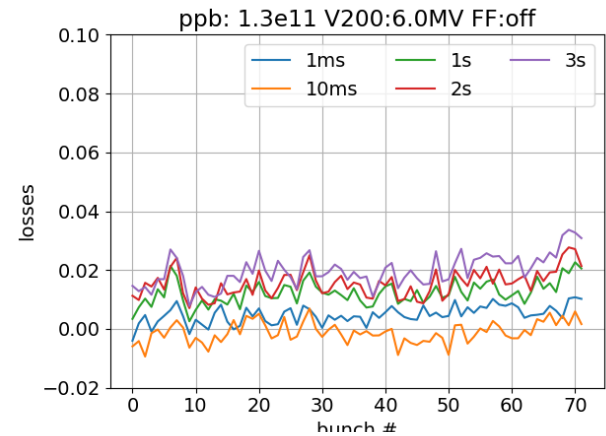
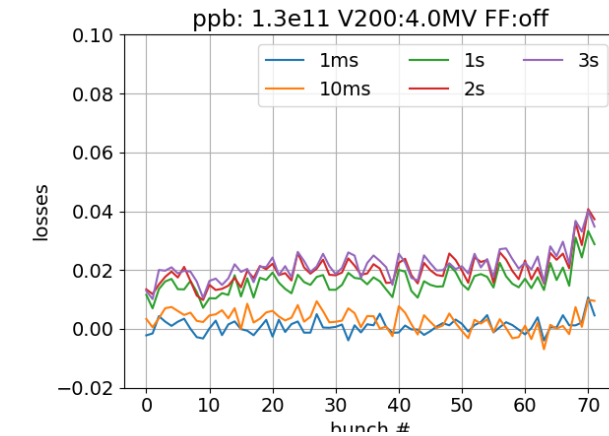
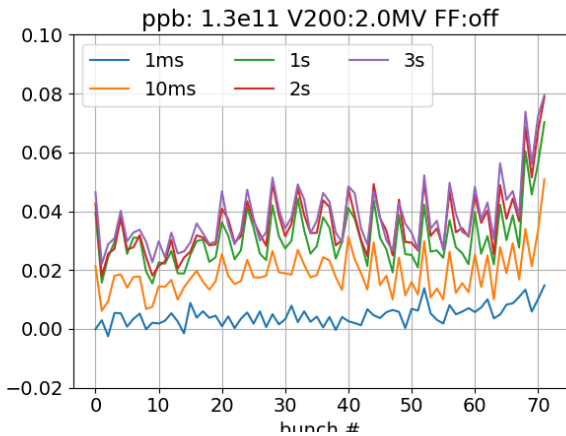
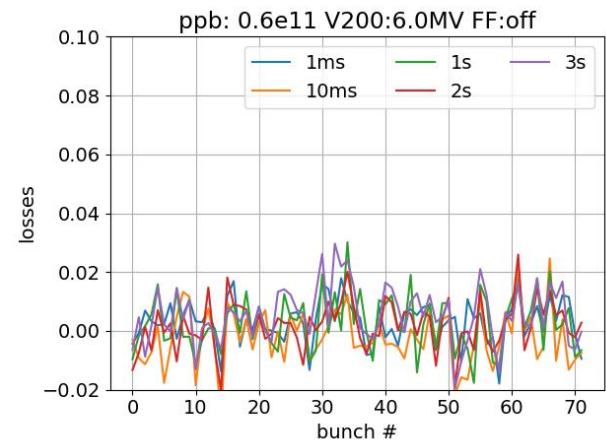
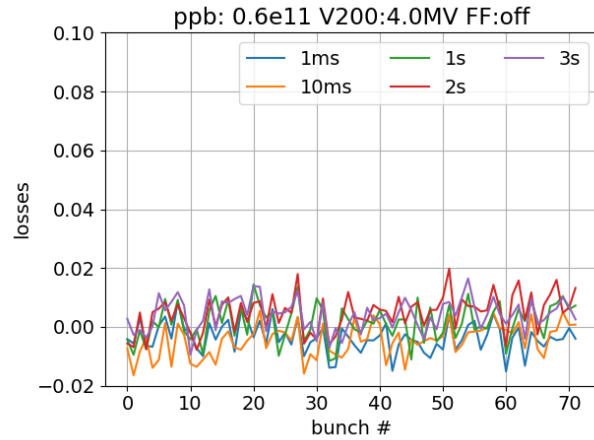
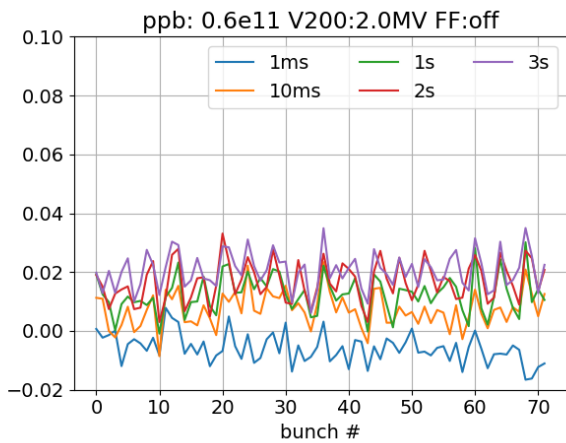
Measurement with different V_{200}

- 72 bunches, 25ns spacing, $1.3e11$ particles per bunch
- LHC25 (Q20), $V_{800} = 0.1 V_{200}$
- Flat-bottom 0-11.1s, data up to first part of ramp (11.830s ~ 29 GeV)
- Capture at $V_{200}=4.5\text{MV}$ (nominal case), **change V_{200} at flat-bottom** (ramp 50ms to 100ms after injection and at 10.75s)



- Limited by momentum aperture (details talk by V. Kain) in Q20
- Less losses for smaller transverse emittance -> use BCMS (only 48 bunches)

Measured loss patterns, measured for different V200 and intensity



Status of OTFB

Measurements:

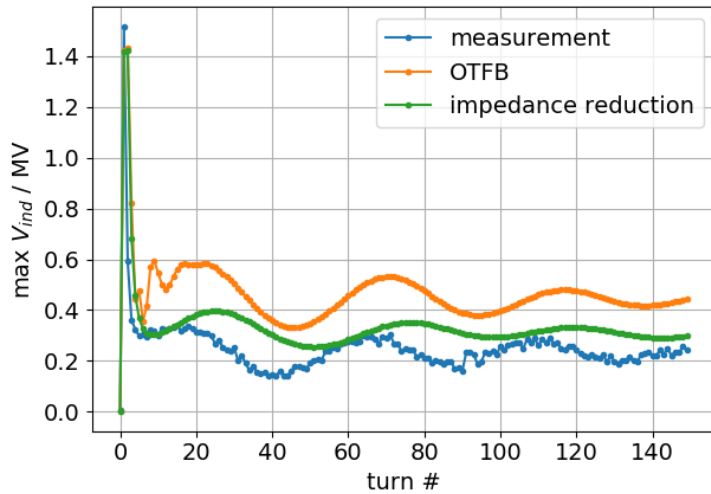
- 48 bunches, 1.48e11 ppb
- $V_{200} = 4.5$ MV, Q22 optic

Simulation parameters:

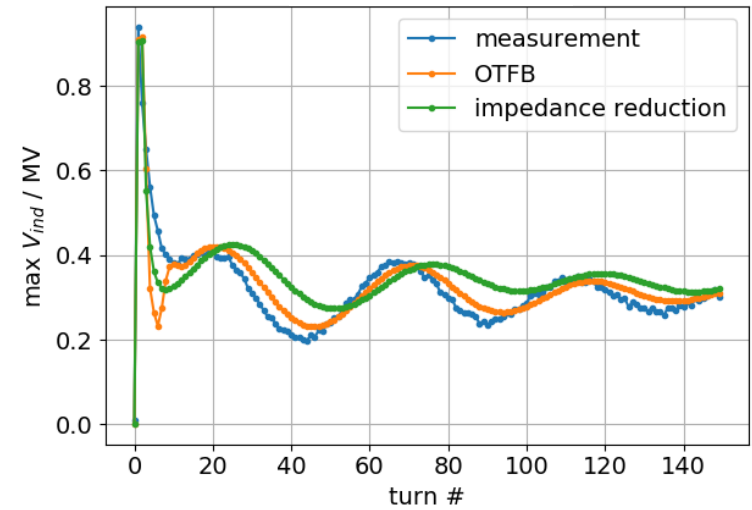
- 48 bunches, 1e6 macro-particles per bunch
- $V_{200} = 4.5$ MV, Q22 optic
- Present full SPS impedance model

Present 'best settings' ($G_{LLRF_4} = 8.0$, $G_{LLRF_5} = 10.0$)

long cavity



short cavity



Results:

- Induced voltage in short TWC 'undershoots' around turn 10; asymptotic behavior represented well
- For long TWC, OTFB does not reduce induced voltage enough -> gain margin missing